

DATA SHEET D0075 REV. -

SILICON SCHOTTKY RECTIFIER DIE Very Low Forward Voltage Drop

Applications:

• Switching Power Supply • Converters • Free-Wheeling Diodes • Polarity Protection Diode

Features:

- Soft Reverse Recovery at Low and High Temperature
- Very Low Forward Voltage Drop
- Low Power Loss, High Efficiency
- High Surge Capacity
- Guard Ring for Enhanced Durability and Long Term Reliability
- Guaranteed Reverse Avalanche Characteristics
- Electrically / Mechanically Stable during and after Packaging

Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Inverse Voltage 1C5817 1C5819	Vrwm	-	20 45	V
Average Forward Current	I _{O(AV)}	50% duty cycle, rectangular wave form	1	А
Non-Repetitive Avalanche Energy	E _{AS}	T _J = 25°C, I _{AS} = 0.18 A, L = 160mH	2.6	mJ
Repetitive Avalanche Current	l _{ar}	I _{AS} decay linearly to 0 in 1µs <i>f</i> limited by TJ max Va=1.5V _R	0.18	А
Junction Temperature	TJ	-	-55 to+125	°C
Storage Temperature	T _{stg}	-	-55 to+150	°C

Electrical Characteristics:

Characteristics	Symbol	Condition	Max.	Units
Forward Voltage Drop 1C58 1C58		@ 1A, Pulse, TJ = 25 °C	0.45 0.49	V
1C58 1C58	•12	@ 0.1A, Pulse, T _J = 25 °C	0.32 0.34	V
Reverse Current	I _{R1}	$T_J = 25 \degree C$ @V _R = 20V, Pulse, @V _R = 45V, Pulse,	50	μΑ
	I _{R2}	$T_J = 100 \degree C$ @V _R = 20V, Pulse, @V _R = 45V, Pulse,	5	mA
Junction Capacitance 1C58 1C58		$@V_{R} = 5V, T_{C} = 25 \ ^{\circ}C$ f _{SIG} = 1MHz, V _{SIG} = 50mV (p-p)	110 70	pF

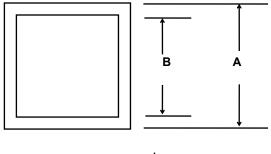
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TECHNICAL DATA DATA SHEET D0075 REV. -

Mechanical Dimensions: In Inches (mm)



_____ +

Bottom side metalization Ag-30kA minimum

Top side metalization AI - 25 kA minimum or Ag - 30 kA minimum. Bottom side is cathode, top side is anode

Dimension H = 0.0105 ± 0.001 (0.27 ± 0.025) for Al top; Dimension H = 0.0155 ± 0.001 (0.39 ± 0.025) for Ag top.

Gold Option Available for Top and/or Bottom Metalization See Part Ordering Information below

Α	В
$0.039 \pm 0.002 (0.99 \pm 0.05)$	$0.032 \pm 0.002 (0.81 \pm 0.05)$

Default part number is Al top, Ag bottom.

Add the following suffix for these metal combinations:

Suffix	Тор	Bottom	Part Number		
	AI	Ag	1C5819		
AG	AI	Au	1C5819AG		
BB	Ag	Ag	1C5819BB		
BG	Ag	Au	1C5819BG		
GG	Au	Au	1C5819GG		
GB	Au	Ag	1C5819GB		

A = Ti (0.3 kA) / Al (25 kA)

B = Ti (1.2 kA) / Ni (1.8 kA) / Ag (30kA)

G = Ti (1.2 kA) / Ni (1.8 kA) / Au (12kA) (TOP) / Ti (1.2 kA) / Ni (1.8 kA) / Au (4kA) (BOTTOM)

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